# STEALTH<sup>™</sup> Rectifier, 30 A, 600 V

#### Description

The ISL9R3060G2–F085 is STEALTH diode optimized for low loss performance in high frequency hard switched applications. The STEALTH family exhibits low reverse recovery current ( $I_{RRM}$ ) and exceptionally soft recovery under typical operating conditions.

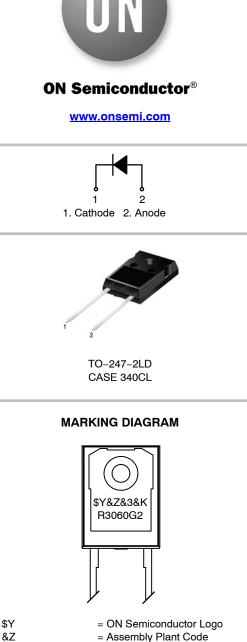
This device is intended for use as a free wheeling or boost diode in power supplies and other power switching applications. The low  $I_{RRM}$  and short  $t_a$  phase reduce loss in switching transistors. The soft recovery minimizes ringing, expanding the range of conditions under which the diode may be operated without the use of additional snubber circuitry. Consider using the STEALTH diode with an SMPS IGBT to provide the most efficient and highest power density design at lower cost.

#### Features

- High Speed Switching  $(t_{rr} = 31 \text{ ns}(Typ.) @ I_F = 30 \text{ A})$
- Low Forward Voltage ( $V_F = 2.4 \text{ V(Max.)} @ I_F = 30 \text{ A}$ )
- Avalanche Energy Rated
- AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

#### Applications

- Automotive DCDC converter
- Automotive On Board Charger
- Switching Power Supply
- Power Switching Circuits



&Z= Assembly Plant Code&3= Date Code (Year & Week)&K= Lot Traceability CodeR3060G2= Specific Device Code

#### **ORDERING INFORMATION**

See detailed ordering and shipping information on page 2 of this data sheet.

Symbol	Parameter	Ratings	Units
VRRM	Peak Repetitive Reverse Voltage	600	V
VRWM	Working Peak Reverse Voltage	600	V
V <sub>R</sub>	DC Blocking Voltage	600	V
IF(AV)	Average Rectified Forward Current $@T_{C} = 125^{\circ}C$	30	A
IFSM	Non-repetitive Peak Surge Current (Halfwave 1 Phase 60 Hz)	325	A
EAVL	Avalanche Energy (1 A, 40 mH)	20	mJ
Тј, Тѕтб	Operating Junction and Storage Temperature	–55 to +175	°C

#### ABSOLUTE MAXIMUM RATINGS $T_C$ = 25°C unless otherwise noted

## THERMAL CHARACTERISTICS $T_C$ = 25°C unless otherwise noted

Symbol	Parameter	Max	Units
Rejc	Maximum Thermal Resistance, Junction to Case	0.58	°C/W
Reja	Maximum Thermal Resistance, Junction to Ambient	45	°C/W

#### PACKAGE MARKING AND ORDERING INFORMATION

Device Marking	Device	Package	Tube	Quantity
R3060G2	ISL9R3060G2-F085	TO-247	-	30

## **ELECTRICAL CHARACTERISTICS** $T_C = 25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Conditions		Min.	Тур.	Max	Units
I <sub>R</sub>	Instantaneous Reverse Current	V <sub>R</sub> = 600 V	$T_{C} = 25^{\circ}C$	-	-	100	μA
			T <sub>C</sub> = 175°C	-	-	2	mA
$V_{FM}^{1}$	Instantaneous Forward Voltage	I <sub>F</sub> = 30 A	T <sub>C</sub> = 25°C	-	2.0	2.4	V
			T <sub>C</sub> = 175°C	-	1.5	2.2	V
t <sub>rr</sub> 2	Reverse Recovery Time	$I_F = 1 \text{ A, } di/dt = 200 \text{ A}/\mu\text{s}, \\ V_{CC} = 390 \text{ V}$	T <sub>C</sub> = 25°C	-	23	35	ns
		$I_F=30~\text{A},~\text{di/dt}=200~\text{A}/\mu\text{s},\\ V_{CC}=390~\text{V}$	T <sub>C</sub> = 25°C T <sub>C</sub> = 175°C	-	31 135	45 -	ns ns
t <sub>a</sub> t <sub>b</sub> Q <sub>rr</sub>	Reverse Recovery Time Reverse Recovery Charge	$    I_{F} = 30 \text{ A, } di/dt = 200 \text{ A}/\mu \text{s,} \\ V_{CC} = 390 \text{ V} $	T <sub>C</sub> = 25°C	- - -	18 13 48	- - -	ns ns nC
E <sub>AVL</sub>	Avalanche Energy	I <sub>AV</sub> =1.0 A, L = 40 mH	-	20	-	-	mJ

Pulse: Test Pulse width = 300 μs, Duty Cycle = 2%.
 Guaranteed by design.

### **TEST CIRCUIT WAVEFORMS**

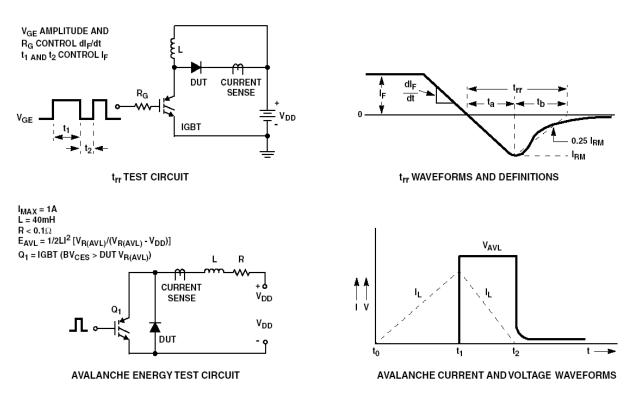
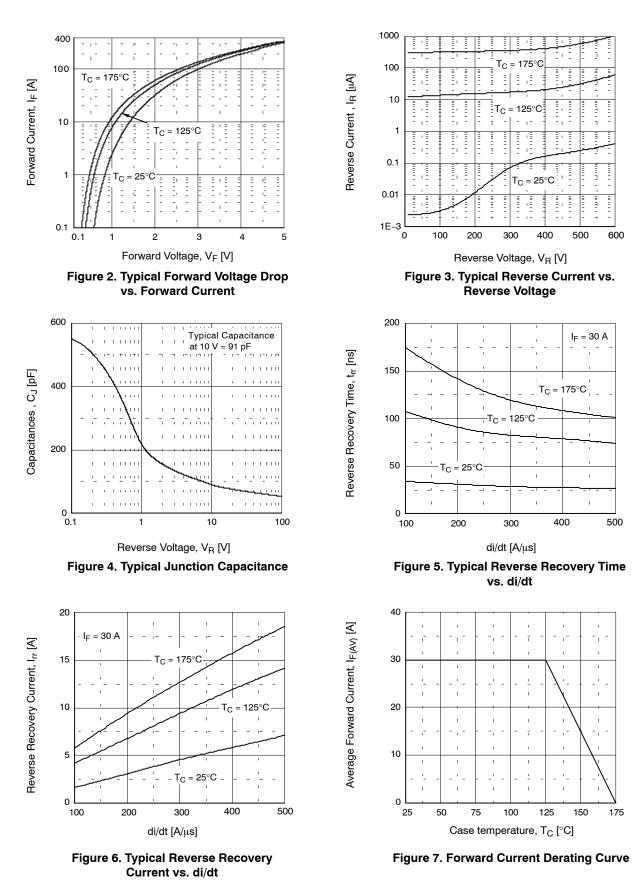
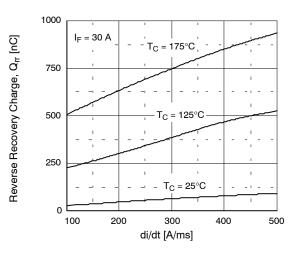


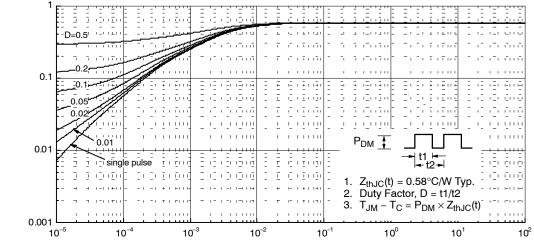
Figure 1.

#### **TYPICAL PERFORMANCE CHARACTERISTICS**









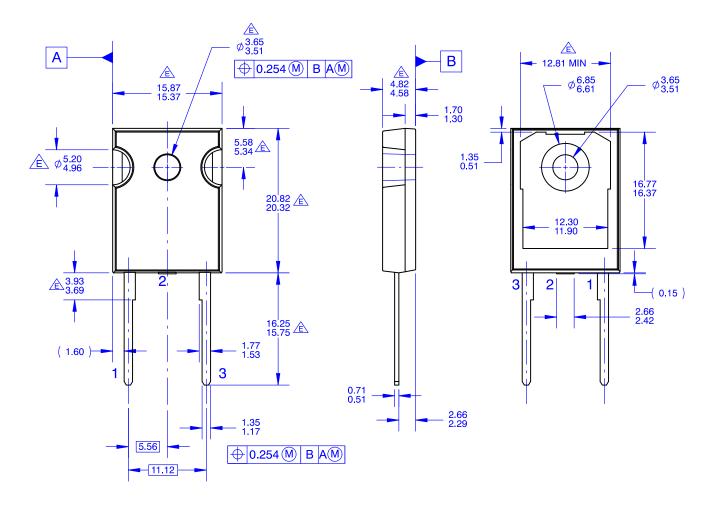
Z<sub>thJC</sub>(t), Thermal Response

t<sub>1</sub>, Square Wave Pulse Duration [sec]

Figure 9. Transient Thermal Response Curve

TO-247-2LD CASE 340CL ISSUE O

DATE 31 OCT 2016



NOTES: UNLESS OTHERWISE SPECIFIED.

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